

MTE8050

Features

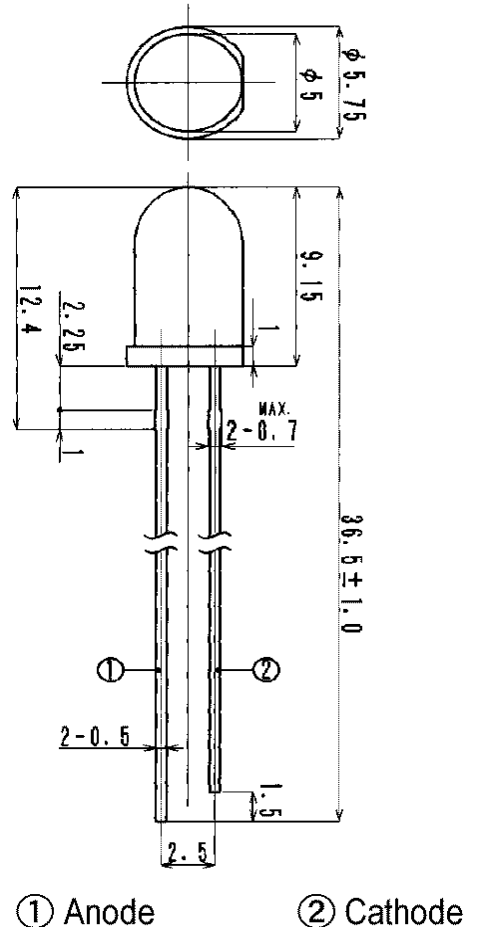
High Output Power
Narrow Beam Angle
High Reliability

Applications

Optical Switches
Optical Sensors

Maximum Ratings (Ta=25°C)

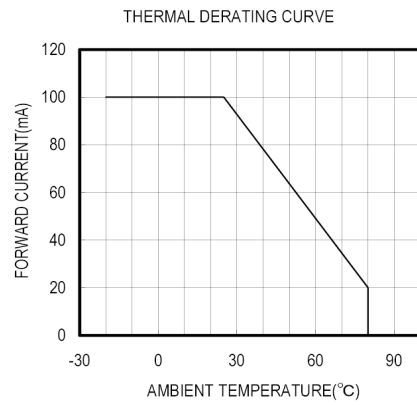
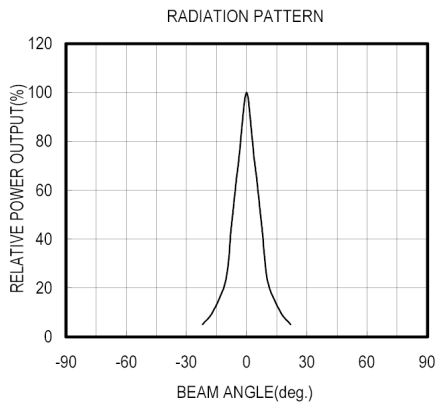
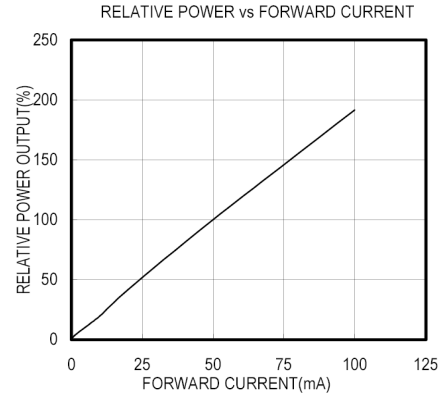
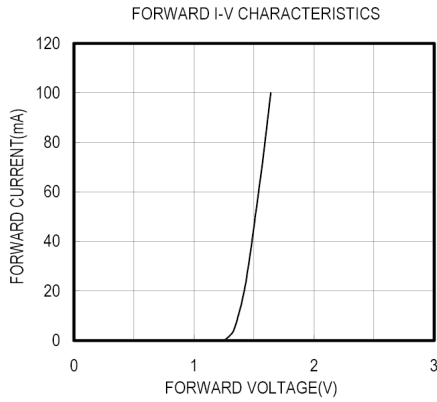
Characteristic	Symbol	Max.	Test Condition	Unit
Forward Current	I _F	100	–	mA
Pulsed Forward Current	I _{FP}	1.00	tw=10μ S, T=10mS	A
Reverse Voltage	V _R	5	–	V
Power Dissipation	P _D	160.00	–	mW
Operating Temperature	T _{opr}	–20 ~ +80	–	°C
Storage Temperature	T _{stg}	–30 ~ +100	–	°C
Soldering Temperature	T _{sol}	260	for 5 sec. max	°C



Opto-Electrical Characteristics (Ta=25°C)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Forward Voltage	V _F	I _F =50mA	–	1.40	1.90	V
Reverse Current	I _R	V _R =5V	–	–	100	μ A
Power Output	PO	I _F =50mA	–	20.00	–	mW
Half Intensity Beam Angle	θ	–	–	± 7°	–	deg.
Peak Wavelength	λ _p	I _F =50mA	–	805	–	nm
Spectral Line Half Width	Δλ	I _F =50mA	–	30	–	nm

MTE8050 Graphs



SPECTRAL OUTPUT

